# **CEUE** NEC'S 1310 nm InGaAsP MQW DFB LASER DIODE IN CAN PACKAGE FOR 155 Mb/s AND 622 Mb/s APPLICATIONS

## NX6306 Series

#### **FEATURES**

- OPTICAL OUTPUT POWER: Po = 5.0 mW
- LOW THRESHOLD CURRENT: ITH = 10 mA @ Tc = 25°C
- HIGH SPEED: tr = 0.5 ns MAX tf = 0.5 ns MAX
- SMSR: 45 dB @ TYP
- WIDE OPERATING TEMPERATURE RANGE: Tc = -40 to +85°C
- InGaAs MONITOR PIN-PD
- CAN PACKAGE: ø5.6 mm
- BASED ON TELCORDIA RELIABILITY

#### DESCRIPTION

NEC's NX6306 Series is a 1310 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode with InGaAs monitor PIN-PD. This device is ideal for Synchronous Digital Hierarchy (SDH) systems and ITU-T recommendations.

## **APPLICATIONS**

- 156 Mb/s: OC-3 (SR, IR-1, LR-1)
- 622 Mb/s: OC-12 (SR, IR-1, LR-1)

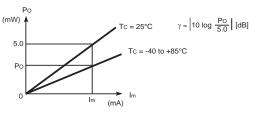
#### ELECTRO-OPTICAL CHARACTERISTICS (Tc = 25°C, unless otherwise specified)

PART NUMBER			NX6306 Series		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	ТҮР	MAX
Vop	Operating Voltage, Po = 5.0 mW, Tc = -40 to +85°C	V	_	1.1	1.6
Ітн	Threshold Current Tc = 85°C	mA mA		10 30	20 40
Ртн	Threshold Output Power, $Tc = -40$ to $+85^{\circ}C$ , $IF = ITH$	μW	-	100	200
ηd	Differential Efficiency (Flat glass type: NX6306S Series) (Aspherical lens type: NX6306G Series)	W/A	0.2 0.2	0.35 0.3	
$\Delta\eta$ d	Temperature Dependence $\Delta\eta d = 10 \log \frac{\eta d (@ 85^{\circ}C)}{\eta d (@ 25^{\circ}C)}$	dB	-3.0	-2.5	-
λρ	Peak Emission Wavelength, Po = 5.0 mW, RMS (-20 dB), Tc = -40 to +85°C	nm	1280	_	1335
SMSR	Side mode Suppression Ratio Po = 5.0 mW, RMS (-20 dB), Tc = -40 to +85°C	dB	30	45	_
θ⊥	Vertical Beam Angle <sup>1</sup> , Po = 5.0 mW, FAHM <sup>2</sup>	deg	-	35	40
$\theta \parallel$	Lateral Beam Angle <sup>1</sup> , Po = 5.0 mW, FAHM <sup>2</sup>	deg	-	30	35
tr	Rise Time, 10 to 90%	ns	-	-	0.5
tr	Fall Time, 90 to 10%	ns	_	_	0.5
Im	Monitor Current, Po = 5.0 mW, VR = 5 V	μΑ	200	600	1000
ld	Monitor Dark Current, $V_R = 5 V$ $V_R = 5 V$ , $T_C = -40$ to $+85^{\circ}C$	nA nA	-	0.1	10 500
Ct	Monitor PD Terminal Capacitance, VR = 5 V, f = 1 MHz	рF	-	6	20
γ	Tracking Error <sup>3</sup> Im = const, (@ Po = 5.0 mW, Tc = $25^{\circ}$ C) Tc = -40 to + $85^{\circ}$ C	dB	-1.0	_	1.0

Notes:

- 1. Applicable only to NX6306S Series.
- 2. FAHM: Full Angle at Half Maximum.

Tracking Error: γ



## **California Eastern Laboratories**

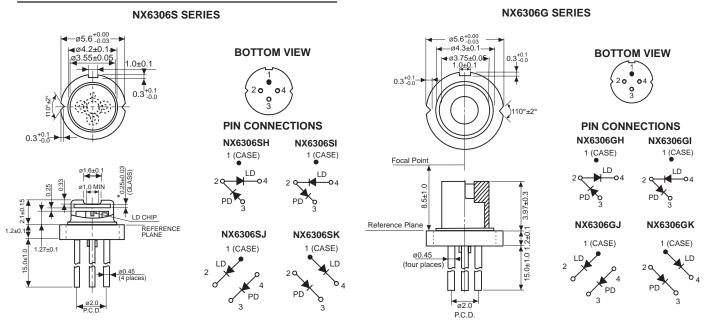
## ABSOLUTE MAXIMUM RATINGS<sup>1</sup>

SYMBOLS	PARAMETERS	UNITS	RATINGS
Po	Optical Output Power	mW	10
lf	Forward Current of LD	mA	150
Vr	Reverse Voltage of LD	V	2.0
lF	Forward Current of PD	mA	10
Vr	Reverse Voltage of PD	V	20
Тс	Operating Case Temperature	°C	-40 to +85
Tstg	Storage Temperature	°C	-40 to +85
TASB	Assembly Temperature	°C	150 (15 Hr)
Tsld	Lead Soldering Temperature	°C	350 (3 sec.)
RH	Relative Humidity (noncondensing)	%	85

Note:

1. Operation in excess of any one of these parameters may result in permanent damage.

## OUTLINE DIMENSIONS (Units in mm)



\*n = 1.48 Bolosilicate Glass

## **ORDERING INFORMATION**

#### NX6306S Series

PART NUMBER	PACKAGE	PIN CONNECTIONS
NX6306SH	4-pin CAN with flat glass cap	
NX6306SI		
NX6306SJ		
NX6306SK		

#### NX6306G Series

PART NUMBER	PACKAGE	PIN CONNECTIONS
NX6306GH	4-pin CAN with aspherical lens cap	
NX6306GI		
NX6306GJ		
NX6306GK		

#### Life Support Applications

These NEC products are not intended for use in life support devices, appliances, or systems where the malfunction of these products can reasonably be expected to result in personal injury. The customers of CEL using or selling these products for use in such applications do so at their own risk and agree to fully indemnify CEL for all damages resulting from such improper use or sale.

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